

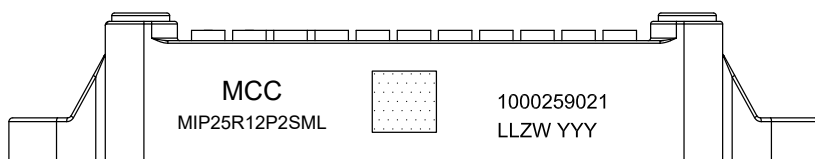
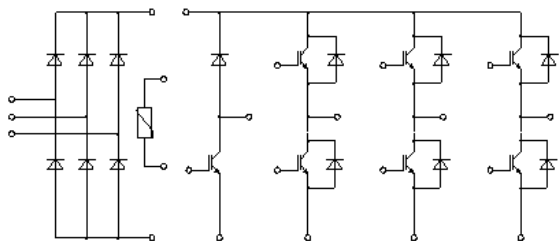
Features

- Low switching losses
- Low $V_{CE(sat)}$ with positive temperature coefficient
- Including fast & soft recovery anti-parallel FWD
- Low inductance case
- High short circuit capability(8us)
- Isolated heatsink using DBC technology
- Maximum junction temperature 175°C
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Applications

- Motor Drivers
- AC and DC Servo Drive Amplifier
- UPS (Uninterruptible Power Supplies)

Circuit Diagram



Marking Code Contents:

Logo: MCC

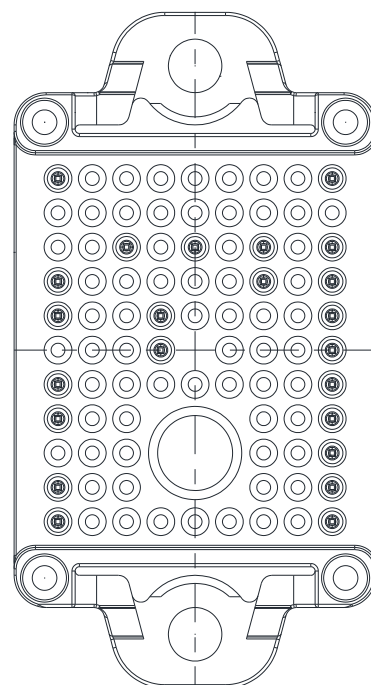
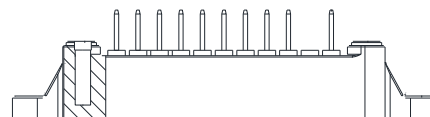
Product Number: MIP25R12P2SML

Trace Code: 10 Digits

2D Code format: Data Matrix

IGBT Modules 1200V 25A

P2S



● IGBT- Inverter

Maximum Ratings

Parameter	Symbol	Test Conditions	Rating	Unit
Collector-Emitter Voltage	V_{CES}	$V_{GE}=0V, I_C=1mA, T_{vj}=25^{\circ}C$	1200	V
Continuous Collector Current	I_C	$T_C=100^{\circ}C, T_{vjmax}=175^{\circ}C$	25	A
Repetitive Peak Collector Current	I_{CRM}	$t_p=1ms$	50	A
Gate-Emitter Voltage	V_{GES}	$T_{vj}=25^{\circ}C$	± 20	V
Total Power Dissipation	P_{tot}	$T_C=25^{\circ}C, T_{vjmax}=175^{\circ}C$	150	W

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=0.5mA, T_{vj}=25^{\circ}C$	5.0	5.8	6.6	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=25A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.60		V
		$I_C=25A, V_{GE}=15V, T_{vj}=125^{\circ}C$		1.90		V
		$I_C=25A, V_{GE}=15V, T_{vj}=150^{\circ}C$		2.00		V
Gate Charge	Q_G			0.19		μC
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1MHz, T_{vj}=25^{\circ}C$		2.83		nF
Reverse Transfer Capacitance	C_{res}			0.036		
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA
Turn-On Delay Time	$t_{d(on)}$	$V_{CE}=600V, I_C=25A, V_{GE}=\pm 15V, R_G=6.2\Omega, T_{vj}=25^{\circ}C$		11		ns
Rise Time	t_r			36		
Turn-Off Delay Time	$t_{d(off)}$			153		
Fall Time	t_f			213		
Turn-On Energy	E_{on}			1.42		mJ
Turn-Off Energy	E_{off}			1.72		
Turn-On Delay Time	$t_{d(on)}$	$V_{CE}=600V, I_C=25A, V_{GE}=\pm 15V, R_G=6.2\Omega, T_{vj}=150^{\circ}C$		12		ns
Rise Time	t_r			37		
Turn-Off Delay Time	$t_{d(off)}$			181		
Fall Time	t_f			338		
Turn-On Energy	E_{on}			2.12		mJ
Turn-Off Energy	E_{off}			2.28		
SC Data	I_{SC}	$t_p \leq 8\mu s, V_{GE}=15V, T_{vj}=150^{\circ}C, V_{CC}=600V, V_{CEM} \leq 1200V$		90		A

● Diode- Inverter

Maximum Ratings

Parameter	Symbol	Test Conditions	Rating	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}C$	1200	V
Continuous DC Forward Current	I_F		25	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1ms$	50	A

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=25A, T_{vj}=25^{\circ}C$		2.15		V
		$I_F=25A, T_{vj}=125^{\circ}C$		1.95		V
		$I_F=25A, T_{vj}=150^{\circ}C$		1.85		V
Recovered Charge	Q_{rr}	$I_F=25A, V_R=600V,$ $-di_F/dt=600A/\mu s, T_{vj}=25^{\circ}C$		1.54		μC
Peak Reverse Recovery Current	I_{rr}			14		A
Reverse Recovery Energy	E_{rec}			0.58		mJ
Recovered Charge	Q_{rr}	$I_F=25A, V_R=600V,$ $-di_F/dt=600A/\mu s, T_{vj}=150^{\circ}C$		3.57		μC
Peak Reverse Recovery Current	I_{rr}			20		A
Reverse Recovery Energy	E_{rec}			1.42		mJ

● IGBT- Brake-chopper

Maximum Ratings

Parameter	Symbol	Test Conditions	Rating	Unit
Collector-Emitter Voltage	V_{CES}	$V_{GE}=0V, I_C=1mA, T_{vj}=25^{\circ}C$	1200	V
Continuous Collector Current	I_C	$T_C=100^{\circ}C, T_{vjmax}=175^{\circ}C$	25	A
Repetitive Peak Collector Current	I_{CRM}	$t_p=1ms$	50	A
Gate-Emitter Voltage	V_{GES}	$T_{vj}=25^{\circ}C$	± 20	V
Total Power Dissipation	P_{tot}	$T_C=25^{\circ}C, T_{vjmax}=175^{\circ}C$	135	W

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=0.5mA, T_{vj}=25^{\circ}C$	5.0	5.8	6.6	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=25A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.60		V
		$I_C=25A, V_{GE}=15V, T_{vj}=125^{\circ}C$		1.90		V
		$I_C=25A, V_{GE}=15V, T_{vj}=150^{\circ}C$		2.00		V
Gate Charge	Q_g			0.19		μC
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1MHz, T_{vj}=25^{\circ}C$		2.83		nF
Reverse Transfer Capacitance	C_{res}			0.036		
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA
Turn-On Delay Time	$t_{d(on)}$	$V_{CE}=600V, I_C=25A, V_{GE}=\pm 15V, R_G=6.2\Omega, T_{vj}=25^{\circ}C$		11		ns
Rise Time	t_r			36		
Turn-Off Delay Time	$t_{d(off)}$			153		
Fall Time	t_f			213		
Turn-On Energy	E_{on}			1.42		mJ
Turn-Off Energy	E_{off}			1.72		
Turn-On Delay Time	$t_{d(on)}$	$V_{CE}=600V, I_C=25A, V_{GE}=\pm 15V, R_G=6.2\Omega, T_{vj}=150^{\circ}C$		12		ns
Rise Time	t_r			37		
Turn-Off Delay Time	$t_{d(off)}$			181		
Fall Time	t_f			338		
Turn-On Energy	E_{on}			2.12		mJ
Turn-Off Energy	E_{off}			2.28		
SC Data	I_{SC}	$T_p \leq 8\mu s, V_{GE}=15V, T_{vj}=150^{\circ}C, V_{CC}=600V, V_{CEM} \leq 1200V$		90		A

● Diode- Brake-chopper

Maximum Ratings

Parameter	Symbol	Test Conditions	Rating	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}C$	1200	V
Continuous DC Forward Current	I_F		10	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1ms$	20	A

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=10A, T_{vj}=25^{\circ}C$		2.0		V
		$I_F=10A, T_{vj}=125^{\circ}C$		1.85		V
		$I_F=10A, T_{vj}=150^{\circ}C$		1.80		V
Recovered Charge	Q_{rr}	$I_F=10A, V_R=600V, -di_F/dt=500A/\mu s, T_{vj}=25^{\circ}C$		0.26		μC
Peak Reverse Recovery Current	I_{rr}			11		A
Reverse Recovery Energy	E_{rec}			0.25		mJ
Recovered Charge	Q_{rr}	$I_F=10A, V_R=600V, -di_F/dt=500A/\mu s, T_{vj}=150^{\circ}C$		0.49		μC
Peak Reverse Recovery Current	I_{rr}			13.0		A
Reverse Recovery Energy	E_{rec}			0.50		mJ

● Diode- Rectifier

Maximum Ratings

Parameter	Symbol	Test Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}C$	1600	V
Average output Current 50/60Hz, sine wave	$I_{F(AV)}$	$T_c=100^{\circ}C$	20	A
Maximum RMS Current at Rectifier Output	I_{RMSM}	$T_c=100^{\circ}C$	40	A
Surge Forward Current	I_{FSM}	$V_R=0, t_p=10ms, T_{vj}=25^{\circ}C$	330	A
		$V_R=0, t_p=10ms, T_{vj}=150^{\circ}C$	280	
I^2t -value	I^2t	$V_R=0, t_p=10ms, T_{vj}=25^{\circ}C$	520	A^2s
		$V_R=0, t_p=10ms, T_{vj}=150^{\circ}C$	390	

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Diode Forward Voltage	V_F	$I_F=25A, T_{vj}=150^{\circ}C$		1.0		V
Reverse Current	I_R	$T_{vj}=150^{\circ}C, V_R=1600V$			2.0	mA

● NTC-Thermistor

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Rated Resistance	R_{25}			5.0		k Ω
Deviation of R100	$\Delta R/R$	$T_C=100, R_{100}=493.3\Omega$	-5.0		5.0	%
Power Dissipation	P_{25}				20	mW
B-value	$B_{25/50}$	$R_2=R_{25}\exp[B_{25/50}(1/T_2-1/(298.15K))]$		3375		K

● Module Characteristics($T_c=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Isolation voltage	V_{isol}	$t=1\text{min}, f=50\text{Hz}$	2500			V
Maximum Junction Temperature	T_{jmax}				175	$^{\circ}\text{C}$
Operating Junction Temperature	$T_{\text{vj op}}$		-40		150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-40		125	$^{\circ}\text{C}$
Stray-Inductance-module	L_{SCE}			30		nH
Module Lead Resistance , Terminal to Chip	$R_{\text{cc'+EE'}}$	TC=25 $^{\circ}\text{C}$, per switch		8.0		m Ω
	$R_{\text{AA'+CC'}}$			6.0		
Thermal Resistance Junction to Case	$R_{\theta\text{jc}}$	per IGBT-inverter			1.00	K/W
		per Diode-inverter			1.32	
		per IGBT-brake-chopper			1.11	
		per Diode-chopper			2.20	
		per Diode-rectifier			1.15	
Thermal Resistance Case to Sink	$R_{\theta\text{CS}}$	per Module		0.058		K/W
Mounting Force Per Clamp	F		20		50	N
Weight of Module	G			25		g

Curve Characteristics

Fig1.IGBT Output Characteristics

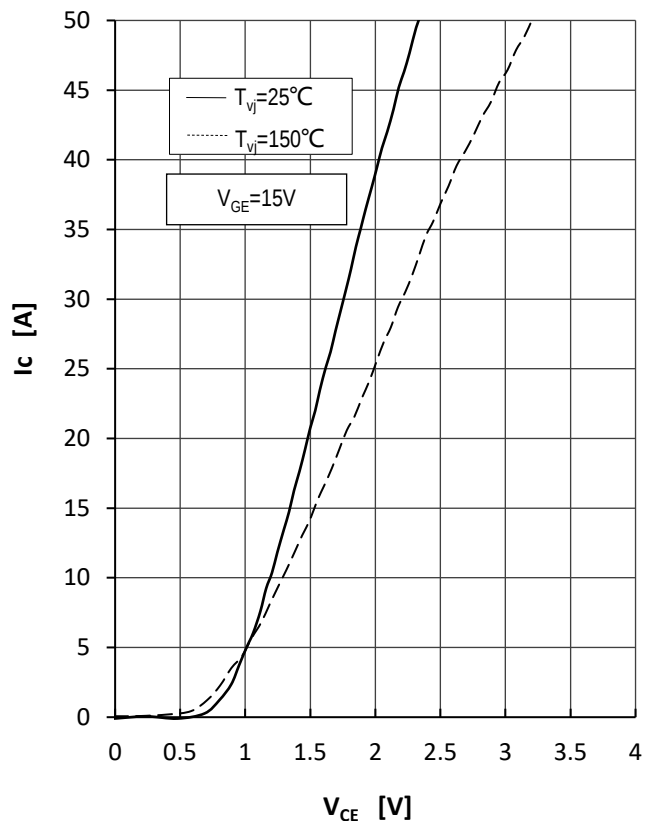


Fig2.IGBT Transfer Characteristics

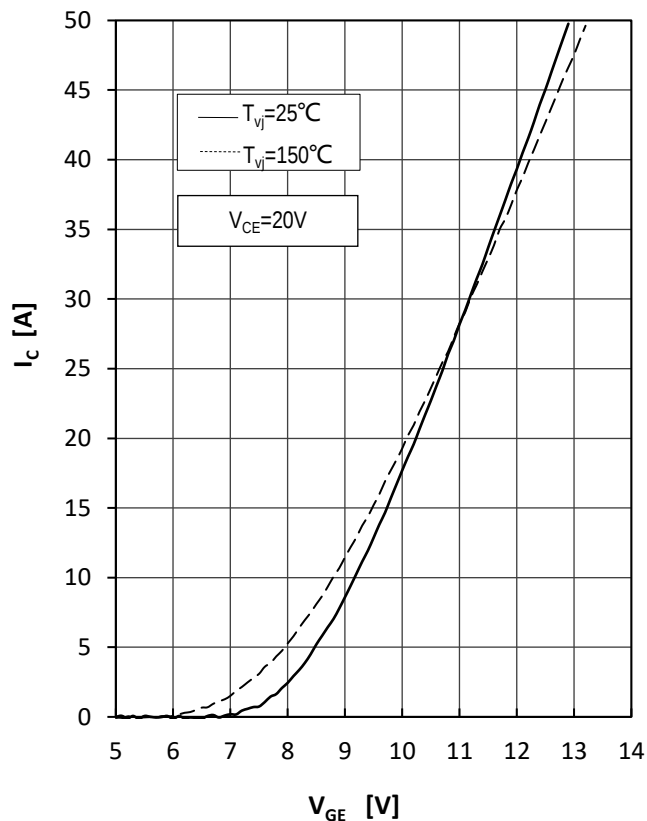


Fig3.IGBT Switching Loss vs.Ic

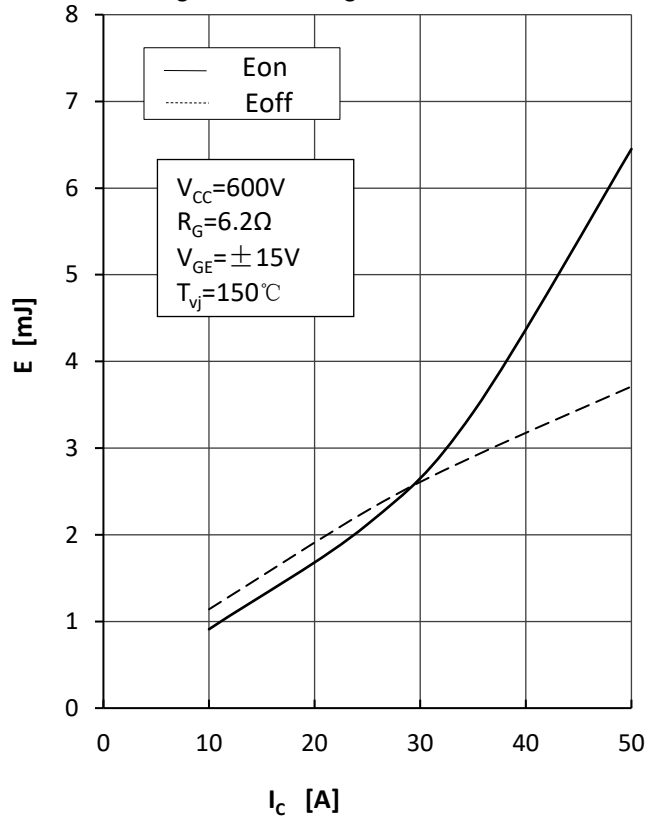
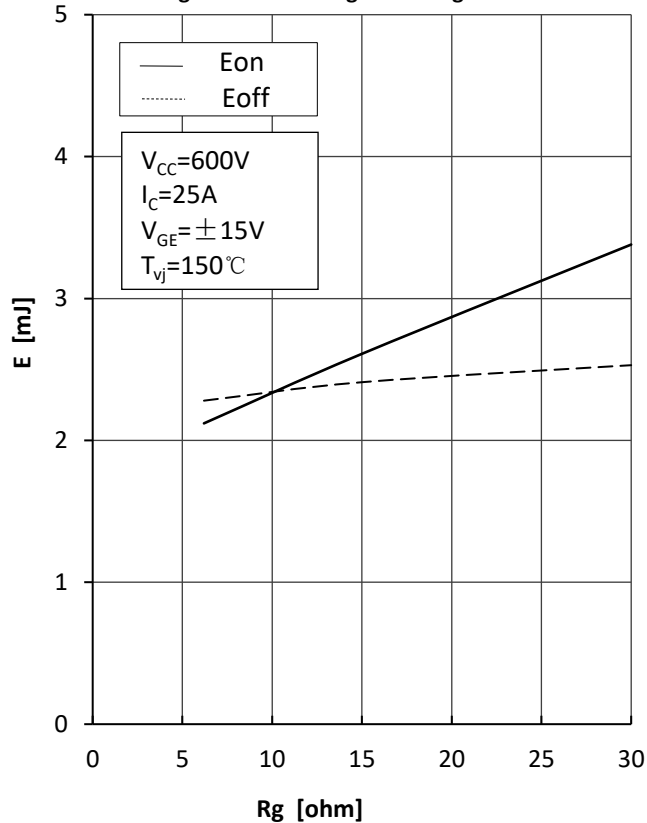


Fig4.IGBT Switching Loss vs.Rg



Curve Characteristics

Fig5. RBSOA

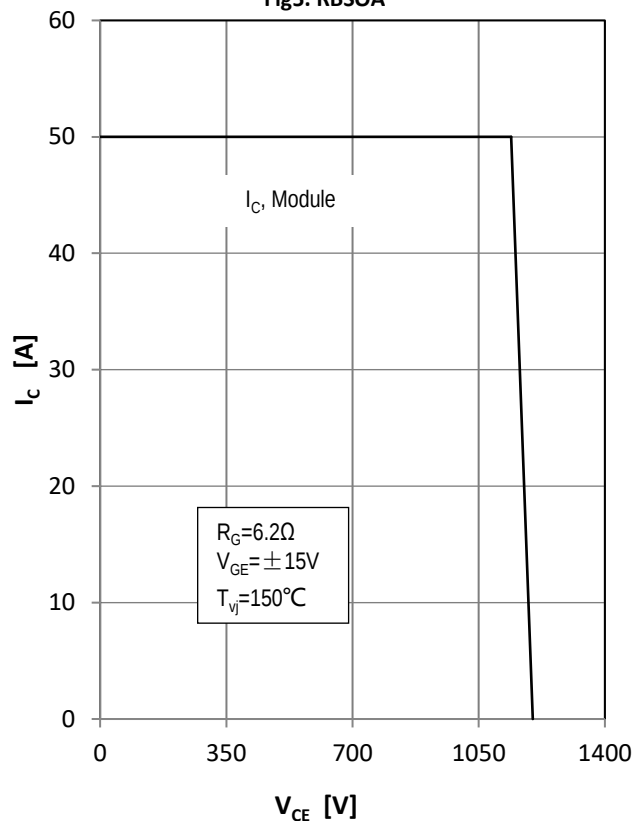


Fig 6. IGBT Transient Thermal Impedance

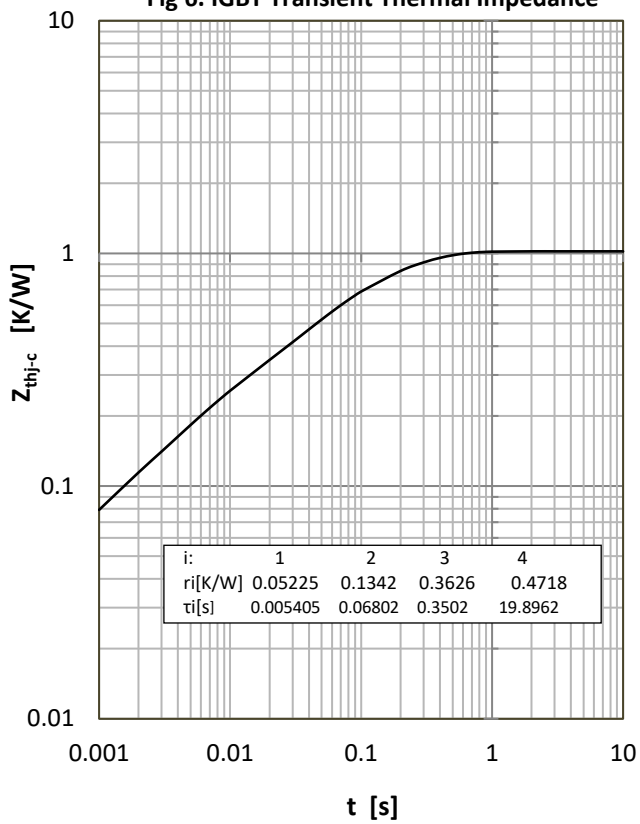


Fig7.Diode Foward Characteristics

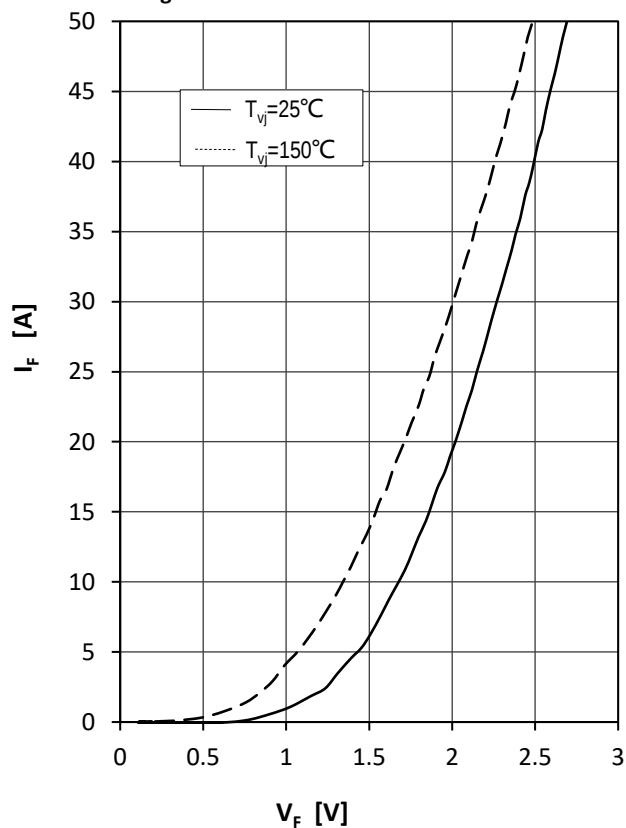
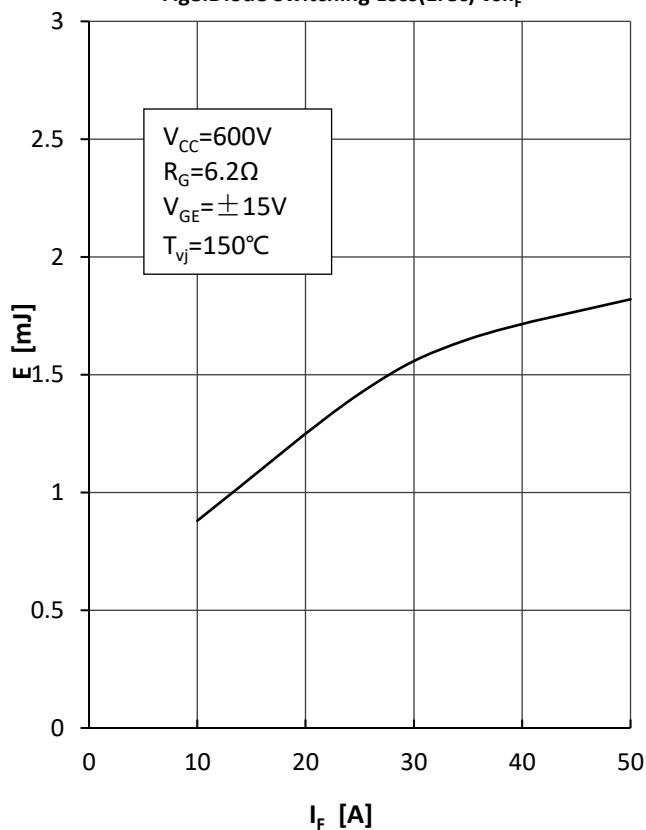


Fig8.Diode Switching Loss(Erec) vs.If



Curve Characteristics

Fig9.Diode Switching Loss(Erec) vs.Rg

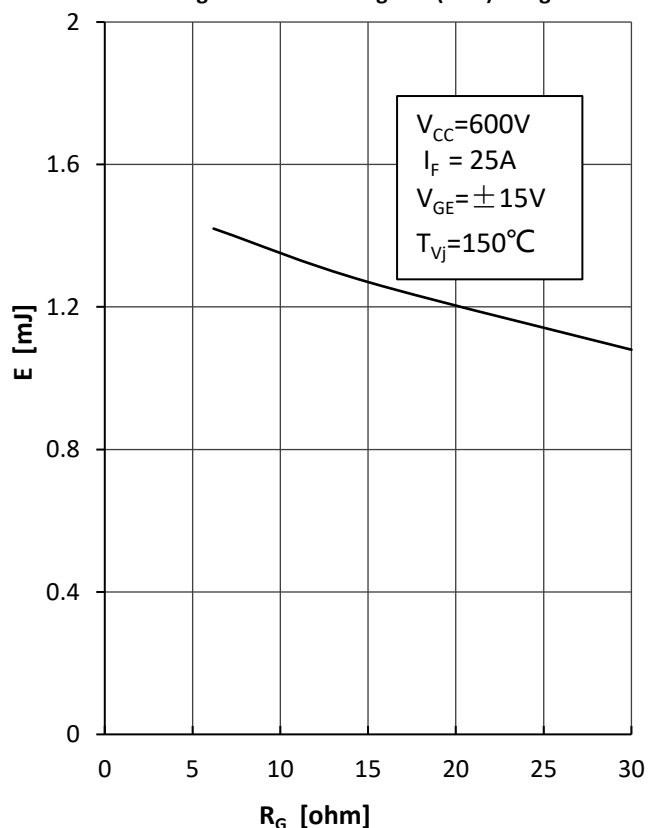


Fig10.Diode Transient Thermal Impedance

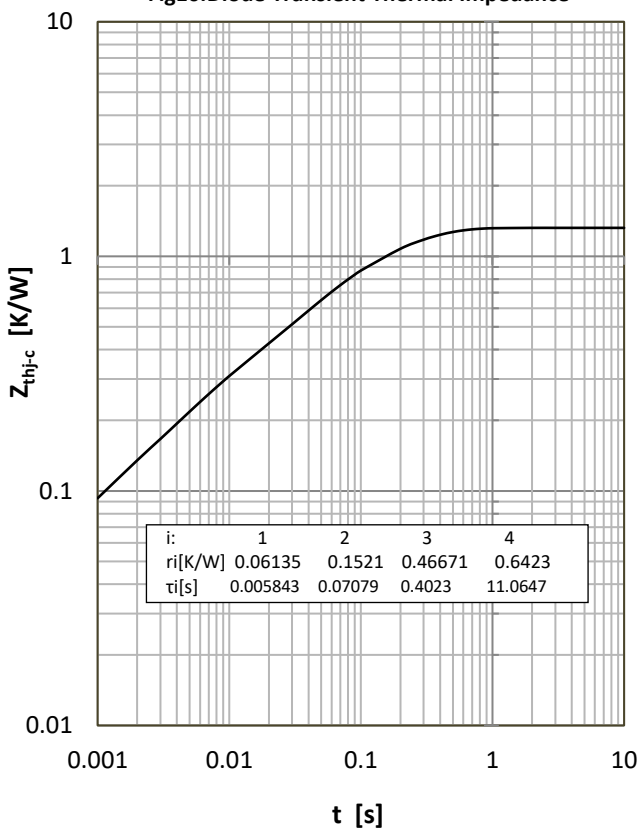


Fig 11. NTC Temperature Characteristic

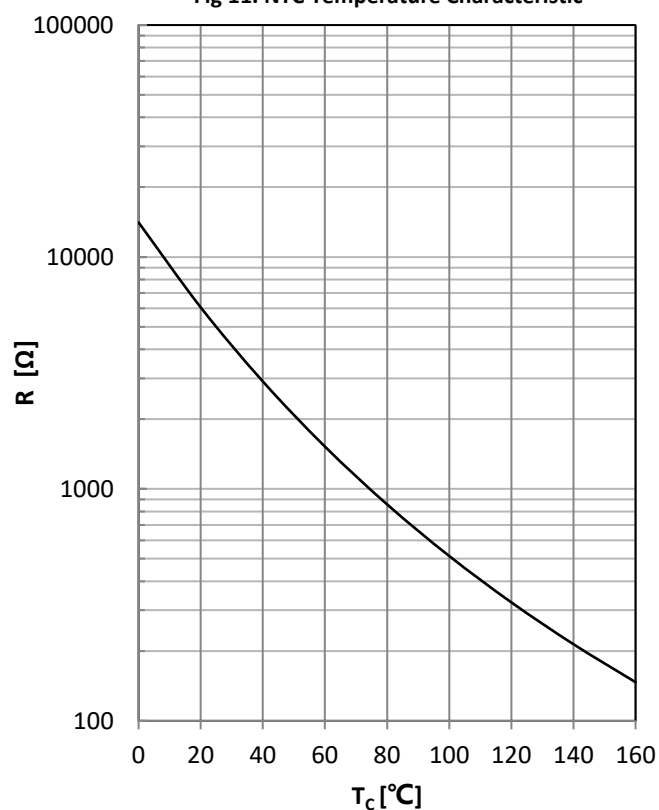
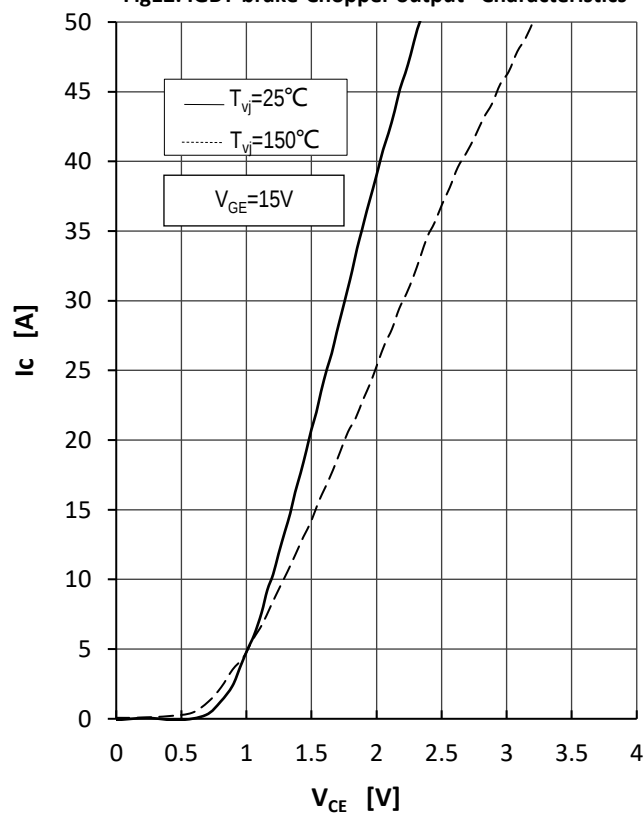


Fig12. IGBT-brake-Chopper output Characteristics



Curve Characteristics

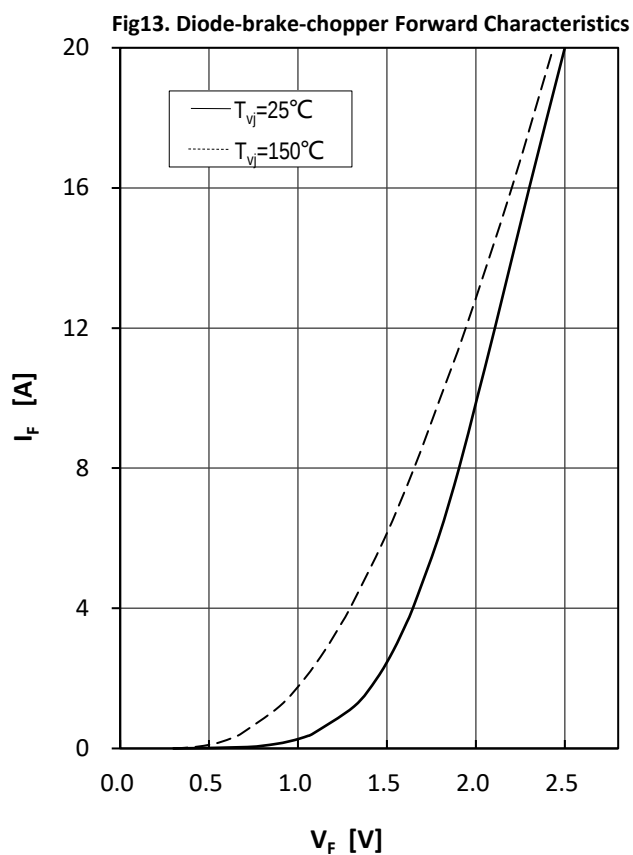
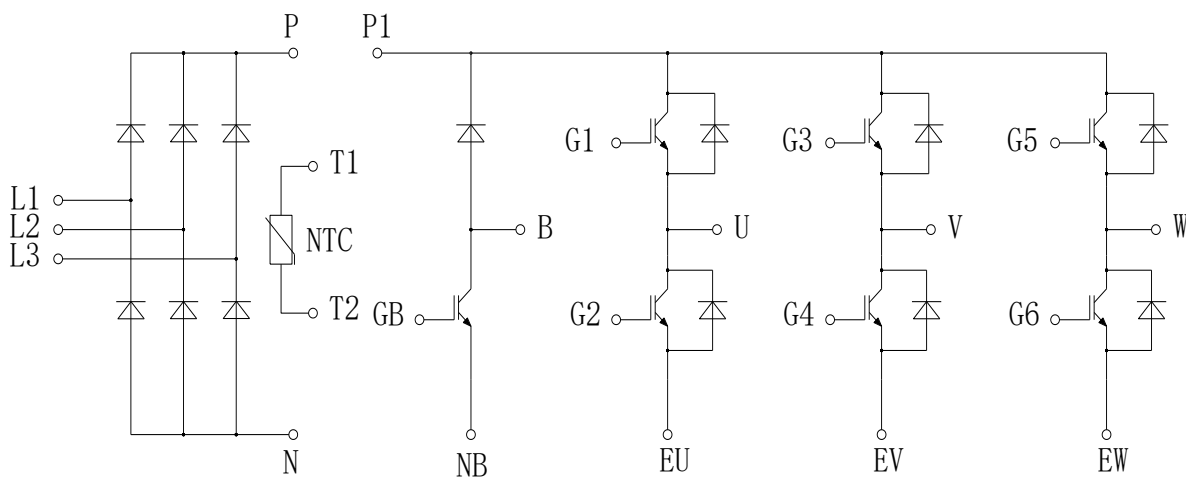
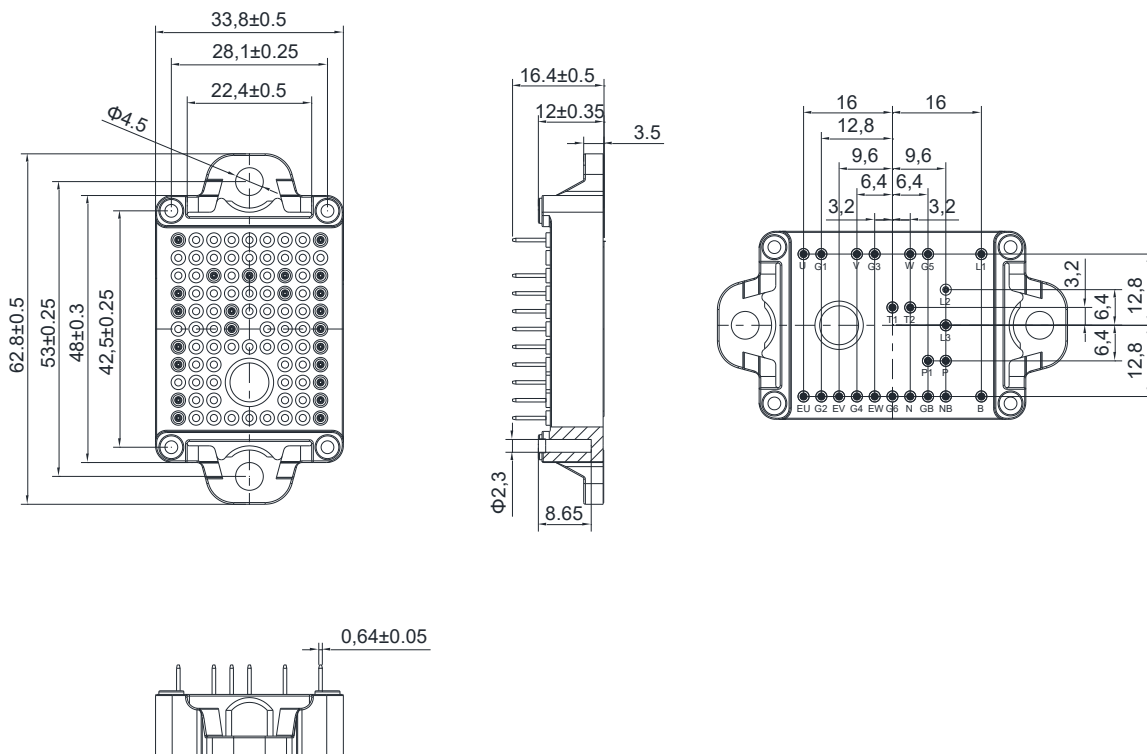


Fig13. Diode-brake-chopper Forward Characteristics

Circuit Diagram



Package Dimensions



Ordering Information

Device	Packing
Part Number-BP	Bulk: 24pcs/Box ; 240pcs/Ctn

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